





Save Time

Save Expense Improve Yields

Semiconductor fabs and OEMs worldwide value the accuracy, precision and versatility of Nordson TEST & INSPECTION's semiconductor measurement devices. The most efficient and effective measurement devices for tool optimization, stabilization and standardization.



Photo reflective of EX-43Q and EX-73Q.

EX-83Q and EX-93Q have one laser diode.

EX-Q

Wafer Mapping Sensor

Metrology Sensors

The EX-Q wafer mapping sensor, featuring reflective laser technology, enables quick and reliable detection of semiconductor wafers and slotting errors in cassettes or FOUPs.

Available in four standoff distances, the EX-Q easily mounts on robots and is adaptable to a wide array of mapping applications, offering both on and off-center wafer scans. It can accommodate mixed wafer batches — for example, dark or coated wafers can be combined with bright wafers — and is compatible with flatted or notched wafers of any size, including 300mm.



EX-Q Wafer Mapping Sensor

Dark or Coated Wafers

Excels at detecting dark or coated wafers at factory gain setting.

- Laser transmitters and receivers are fine-tuned for maximum sensitivity while still maintaining Class 1 status.
- Easy to use "off-the-shelf" direct interface requires no amplification or signal conditioning and reduces tool total cost of ownership.

Reliably Detects

Specifications

Cross-slotted and ultra-thin wafers.

 Thin laser stripe (0.05mm) combined with multiple apertures and spatial filtering reduces noise, improving mapping accuracy.

EX-43Q

 Accommodates all SEMI® standard wafers, regardless of size or edge geometry, through Patented Dual and Wide Beam technologies.

Insensitive to Interference

Insensitive to interference from the mapping environment.

- Beam geometry and built-in ambient light filters minimize stray reflections and ambient lighting influences.
- The non-intrusive wafer mapping solution protects valuable wafers from inadvertent crashes.
- There are no moving parts that can result in particulate contamination.

EX-93Q

For more information, speak with your Nordson representative or contact your Nordson regional office

Nordson Test & Inspection Europe, SEA, Africa

ti-sales-eu@nordson.com

Nordson Test & Inspection Americas

ti-sales-us@nordson.com

Nordson Test & Inspection China

ti-sales-cn@nordson.com

Nordson Test & Inspection Japan

ti-sales-jp@nordson.com

Nordson Test & Inspection Singapore

ti-sales-eu@nordson.com

Nordson Test & Inspection

ti-sales-tw@nordson.com

Nordson Test & Inspection Korea

ti-sales-korea@nordson.com

Method of Detection	Dual Wide Beam		Wide Beam	
Optimum Detecting Distance	1.5"	2.2"	3.0"	4.5"
Maximum Detecting Range	1.4" to 1.6"	2.05" to 2.35"	2.8" to 3.2"	4.2" to 4.8"
Supply Voltage	9 to 24V DC			
Current Consumption	130 mA typical, 200 mA max.			
Light Source	2 X 850 nm diode lasers		1 X 850 nm diode lasers	
- at Exit Port	2 X 0.600 mW max.		1 X 0.600 mW max.	
- at CDRH Aperture	0.077 mW max.		0.077 mW max.	
Laser Class	Class 1 (CDRH)			
Detectable Objects	Transparent, opaque and mirror-surfaced objects			
Laser Spot Size	10mm x 0.05mm	16mm x 0.06mm	15mm x 0.09mm	22mm x 0.14mm
Working Angle Range	± 16 degrees relative to the sensor front surface	± 11 degrees relative to the sensor front surface	-4 to +8 degrees relative to the sensor front surface	
Operation	Light-ON/Dark-ON switch, Enable, Gain setting			
Response Time	400-μs max.			
Minimum Pulse Width	5 msec. (Options available)			
Indicator	Laser power - RED led, Signal OUT - GREEN led			
Control Output	MOSFET open drain, Low-True, 80mA max @24V DC			
Connections	16", 4 conductor cable (Options available)			
Temperature	Operating: 32 to 104°F (0 to 40°C) Storage: -20 to 130°F (-30 to 55°C)			

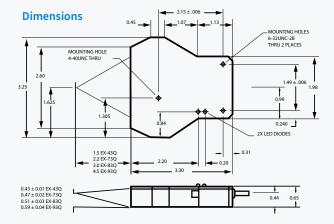
Operating: 32 to 104°F (0 to 40°C) Storage: -20 to 130°F (-30 to 55°C)

Lenses: glass, plastic; Case: aluminum

4.3 oz (122g)

EX-73Q

EX-83Q



Careful alignment and adjustment of the sensor is required for optimal performance. Read the instructions before installation. Failure to properly install, align, or use the EX-Q wafer mapping sensor may reduce its performance.

EX-Q laser photoelectric sensors contain no user-serviceable parts. Refer all servicing to Nordson Corporation. Semiconductor lasers used in the EX-Q wafer mapping sensor generate Class 1 invisible laser radiation. Avoid looking directly at the laser beam.

These sensors conform to IEC 60825-1 (2001-08) (laser safety) and to the laser safety requirements of SEMI S2-0200.



Limits

Materials

Weight